

MP6924, MP6924A

Fast Turn-off. **CCM/DCM** Compatible **Dual LLC Synchronous Rectifier** with low Sleep Mode Current

DESCRIPTION

The MP6924, MP6924A is a dual, fast turn-off, intelligent rectifier for synchronous rectification in LLC resonant converters.

The IC drives two N-channel MOSFETs. regulates their forward voltage drop to V_{fwd}(MP6924:45mV,MP6924A:29mV), and turns the MOSFETs off before the switching current goes negative.

The MP6924, MP6924A has a light-load function to latch off the gate driver under lightload conditions, limiting the current to 175µA.

The MP6924, MP6924A's fast turn-off enables both continuous conduction mode (CCM) and discontinuous conduction mode (DCM).

The MP6924, MP6924A requires a minimal number of readily available, standard, external components and is available in a SOIC-8 package.

| Turn-off Blanking | 1.75µs vs. 210ns | | |
|--------------------|-------------------------------------|--|--|
| Time | Improve noise immunity | | |
| Driving Capability | Be half Improve EMI performance | | |
| Forward Voltage | 29mV vs. 45mV Improve efficiency | | |

TYPICAL APPLICATION

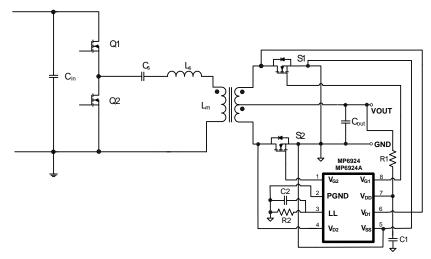
FEATURES

- Works with Standard and Logic Level **MOSFETs**
- Compatible with Energy Star •
- Fast Turn-Off Total Delay of 35ns •
- Wide 4.2V ~ 35V V_{DD} Operating Range •
- 175µA Low Quiescent Current in Light-Load • Mode
- Supports CCM, CrCM, and DCM Operation
- Supports High-Side and Low-Side Rectification
- Power Savings of Up to 1.5W in a Typical • Notebook Adapter
- Available in a SOIC-8 Package

APPLICATIONS

- AC/DC Adapters
- PC Power Supplies
- LCD and LED TVs
- Isolated DC/DC Power Converters

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ORDERING INFORMATION

| Part Number* | Package Top Marketing | | |
|--------------|-----------------------|-----------|--|
| MP6924GS | | See Below | |
| MP6924AGS | SOIC-8 | | |

* For Tape & Reel, add suffix –Z (e.g. MP6924GS–Z)

TOP MARKING (MP6924GS)

MP6924 LLLLLLLL MPSYWW

MP6924: Part number LLLLLLL: Lot number MPS: MPS prefix Y: Year code WW: Week code

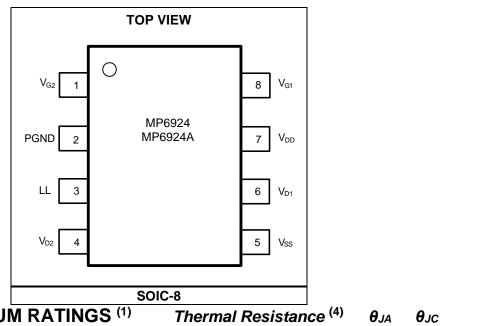
TOP MARKING (MP6924AGS)

MP6924A LLLLLLLL MPSYWW

MP6924A: Part number LLLLLLL: Lot number MPS: MPS prefix Y: Year code WW: Week code



PACKAGE REFERENCE



ABSOLUTE MAXIMUM RATINGS (1)

| V_{DD} to V_{SS} | 0.3V to +38V |
|-----------------------------------|---|
| PGND to V _{SS} | 0.3V to +0.3V |
| V _G to V _{SS} | 0.3V to +20V |
| V_D to V_{SS} | 1V to +180V |
| LL to V _{SS} | 0.3V to +6.5V |
| Continuous power dissipation | (T _A = +25°C) ⁽²⁾ |
| SOIC-8 | 1.4W |
| Junction temperature | 150°C |
| Lead temperature (solder) | 260°C |
| Storage temperature | 55°C to +150°C |

Recommended Operation Conditions (3)

 SOIC-89045 ...°C/W

NOTES:

- 1) Exceeding these ratings may damage the device.
- 2) The maximum allowable power dissipation is a function of the maximum junction temperature T_J(MAX), the junction-toambient thermal resistance θ_{JA} , and the ambient temperature T_A. The maximum allowable continuous power dissipation at any ambient temperature is calculated by P_D(MAX)=(T_J(MAX)-T_A)/ θ_{JA} . Exceeding the maximum allowable power dissipation produces an excessive die temperature, causing the regulator to go into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage.
- The device is not guaranteed to function outside of its operating conditions.
- 4) Measured on JESD51-7, 4-layer PCB.

ELECTRICAL CHARACTERISTICS

 V_{DD} = 12V, -40°C \leq T_J \leq +125°C, unless otherwise noted.

| Parameter | | Symbol | Conditions | Min | Тур | Max | Units |
|---|-----------------------|-------------------|--|------|------------|------------|-------|
| V _{DD} voltage range | | | | 4.2 | | 35 | V |
| V _{DD} UVLO rising | | | | 3.7 | 3.95 | 4.2 | V |
| V _{DD} UVLO hysteresis | | | | 0.13 | 0.185 | 0.24 | V |
| Operating current | | lcc | C _{LOAD} = 4.7nF, F _{SW} = 100kHz | | 16 | 20 | mA |
| Quiescent current | | lq | $V_{SS} - V_D = 0.5V$ | | 4.6 | 6 | mA |
| Shutdown current | | | $V_{DD} = 4V, LL = 0V$ $V_{DD} = 20V, LL = 0V$ | | 135 155 | 190 210 | μA |
| Light-load mode current | | | | | 175 | 225 | μA |
| Thermal shutdown ⁽⁵⁾ | MP6924 MP6924A | | | | 150 175 | | °C |
| Thermal shutdown hyste | eresis ⁽⁵⁾ | | | | 10 | | °C |
| Control Circuitry Section | | l | | | | I | I |
| Vss - Vp forward | MP6924 | | | 28 | 45 | 58 | |
| voltage | MP6924A | V _{fwd} | | 17 | 29 | 41 | mV |
| Turn off threshold (Vss - | V _D) | | | -56 | -40 | -20 | mV |
| | MP6924 | | | | 80 | 140 | |
| Turn on dolov | MP6924A | t _{Don} | $C_{LOAD} = 4.7 nF, V_{GS} = 2V$ | | 190 | 300 | ns |
| Turn-on delay | MP6924 | t- | $C_{LOAD} = 10$ nF, $V_{GS} = 2V$ | | 90 | 180 | |
| | MP6924A | t _{Don} | | | 270 | 410 | ns |
| Input bias current on V _D | | | V _D = 180V | | | 1 | μA |
| Turn-on blanking time | | t _{B_ON} | $C_{LOAD} = 4.7 nF$ | 0.75 | 1.1 | 1.65 | μs |
| Turn-off blanking time | MP6924 | | 0 4.755 | | 210 | | ns |
| (5) | MP6924A | - tb_off | $C_{LOAD} = 4.7 nF$ | | 1750 | | |
| Turn-off blanking V _{DS} threshold(MP6924A disabled) | | V_{B_OFF} | | 1 | 1.7 | 2.5 | V |
| Light-load enter pulse width | | Τιι | R _{LL} = 100kΩ | 1.7 | 2.3 | 3 | μs |
| Light-load turn-on pulse width hysteresis | | T _{LL-H} | $R_{LL} = 100 k\Omega$ | | 0.45 | | μs |
| Light logal optage dalage | MP6924 | - - | | 0.5 | 1 | 1.52 | ms |
| Light-load enter delay | MP6924A | T _{LL-D} | | 45 | 78 | 121 | μs |
| Gate disable threshold on LL | | V_{LL_DIS} | | 0.1 | 0.2 | 0.3 | V |
| Turn-on threshold (V _{DS}) | | VLL_DS | V _{DD} = 12V | -330 | -230 | -130 | mV |
| Gate Driver Section | | | | | | | |
| V _G (low) | | V _{G_L} | ILOAD = 1mA | | | 0.1 | V |
| V _a (high) | | Volu | V _{DD} > 10V | | 11.5 | 13 | V |
| V _G (high) | | V _{G_} н | V _{DD} ≤ 10V | | Vdd | | |
| Turn-off propagation delay | | | V _D = V _{SS} | | 15 | | ns |
| Turn-off total delay | | t _{Doff} | $V_D = V_{SS}, C_{LOAD} = 4.7 nF,$ $R_{GATE} = 0\Omega, V_{GS} = 2V$ | | 35 | 80 | ns |
| | | t _{Doff} | $ V_D = V_{SS}, C_{LOAD} = 10nF, \\ R_{GATE} = 0\Omega, V_{GS} = 2V $ | | 45 | 100 | ns |
| Maximum source | MP6924 | | | | 0.5 | | ۸ |
| current ⁽⁶⁾ | MP6924A | 1 | | | 0.13 | 1 | A |
| Pull-down impedance | | | | | 0.6 | 1.5 | Ω |

NOTES:

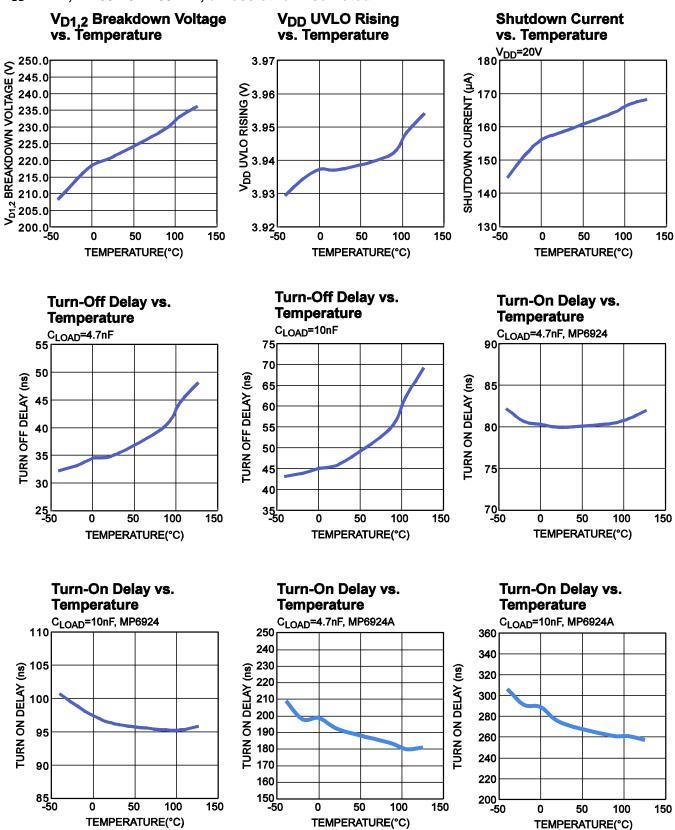
5) Guaranteed by characterization. 6) Guaranteed by design.

MP6924, MP6924A Rev. 1.02 9/15/2017 MPS Proprietary In www.MonolithicPower.com

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TYPICAL PERFORMANCE CHARACTERISTICS

V_{DD} = 12V, MP6924/MP6924A, unless otherwise noted.

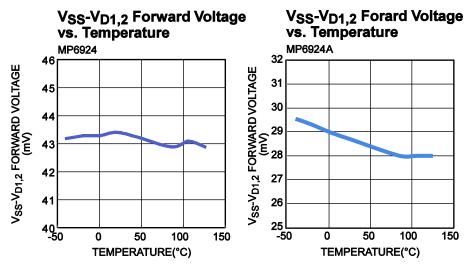


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TYPICAL PERFORMANCE CHARACTERISTICS (continued)

V_{DD} = 12V, unless otherwise noted.



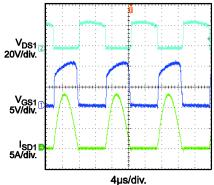
2µs/div.

TYPICAL PERFORMANCE CHARACTERISTICS (continued)

V_{DD} = 12V, unless otherwise noted.

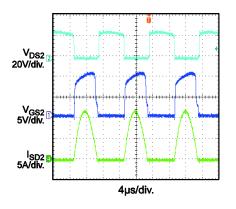
Operation in 90W LLC Converter VIN=240VAC, V_{OUT}=12V, I_{OUT}=0.75A Operation in 90W LLC Converter VIN=240VAC, V_{OUT}=12V, I_{OUT}=0.75A Operation in 90W LLC Converter VIN=240VAC, V_{OUT}=12V, I_{OUT}=0.75A Overation in 90W LLC Converter VIN=240VAC, V_{OUT}=12V, I_{OUT}=0.75A

Operation in 90W LLC Converter V_{IN}=240VAC, V_{OUT}=12V, I_{OUT}=7.5A



Operation in 90W LLC Converter VIN=240VAC, VOUT=12V, IOUT=7.5A

2µs/div.





PIN FUNCTIONS

| Pin # (SOIC-8) | Name | Description |
|-------------------|-----------------|---|
| 1 | V_{G2} | MOSFET 2 gate driver output. |
| 2 | PGND | Power ground. PGND is the power switch return. |
| 3 | LL | Light-load timing setting. Connect a resistor to LL to set the light-load timing. Leave LL open to prevent the IC from entering light-load mode. Pull LL low to disable the gate driver. |
| 4 | V _{D2} | MOSFET 2 drain voltage sense. |
| 5 | Vss | Source pin used as reference for V _{D1} and V _{D2} . |
| 6 | V _{D1} | MOSFET 1 drain voltage sense. |
| 7 | Vdd | Supply voltage. |
| 8 | V_{G1} | MOSFET 1 gate driver output. |



BLOCK DIAGRAM

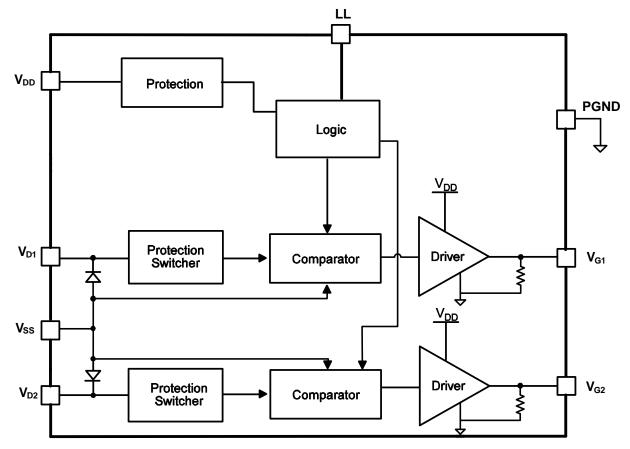


Figure 1: Functional Block Diagram



OPERATION

MP6924. MP6924A The operates in (DCM), discontinuous conduction mode continuous conduction mode (CCM), and critical conduction mode (CrCM). When the MP6924, MP6924A operates in either DCM or CrCM, the control circuitry controls the gate in forward mode, and the gate turns off when the MOSFET current is low. In CCM, the control circuitry turns off the gate during very fast transients.

VD Clamp

Because $V_{D1,2}$ can go as high as 180V, a highvoltage JFET is used at the input. To prevent excessive currents when $V_{DS1,2}$ goes below -0.7V, a 1k Ω resistor is recommended between $V_{D1,2}$ and the drain of the external MOSFET.

Under-Voltage Lockout (UVLO)

When V_{DD} is below the V_{DD} UVLO threshold, the MP6924, MP6924A falls into sleep mode and $V_{G1,2}$ remains at a low level.

Enable

If LL is pulled low, the MP6924, MP6924A is in shutdown mode, which consumes 175μ A of shutdown current. If LL is pulled high during the rectification cycle, the gate driver will not appear until the next rectification cycle begins (see Figure 2).

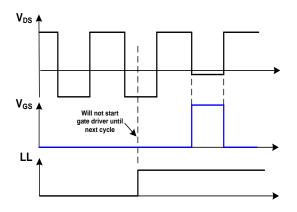


Figure 2: LL Control Scheme

Thermal Shutdown

If the junction temperature of the chip exceeds thermal shutdown threshold, $V_{G1,2}$ is pulled low, and the MP6924, MP6924A stops switching. The IC resumes normal function after the junction temperature drops 10°C.

Turn-On Phase

When the switch current flows through the body diode of the MOSFET, there is a negative voltage drop ($V_D - V_{SS}$) across the body diode. V_{DS} is much lower than the turn-on threshold of the control circuitry (V_{LL-DS}), which triggers a maximum 500mA of charge current to turn on the MOSFET (see Figure 3).

Turn-On Blanking

The control circuitry contains a blanking function that ensures that when the MOSFET turns on or off, it remains in that state for t_{B_ON} (~1.1µs), which determines the minimum on time. During the turn-on blanking period, the turn-off threshold is not blanked completely, but changes to about +100mV (instead of +40mV). This ensures that the part can always turn off, even during the turn-on blanking period, although it does so slower. Avoid setting the synchronous period below t_{B_ON} in CCM condition in the LLC converter to eliminate shoot-through.

Conduction Phase

When V_{DS} rises above the forward voltage drop (- V_{fwd}) according to the decrease of the switching current, the MP6924, MP6924A pulls down the gate voltage level to make the on resistance of the synchronous MOSFET larger to ease the rise of V_{DS} .

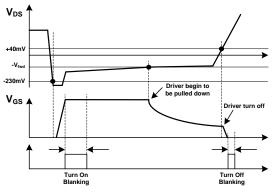


Figure 3: Turn-On/-Off Timing Diagram

The control scheme in Figure 3 shows V_{DS} adjusted to be around $-V_{fwd}$, even when the current through the MOSFET is fairly low. This function puts the driver voltage at a very low level when the synchronous MOSFET is turning off, which boosts the turn-off speed.

Turn-Off Phase

When V_{DS} rises to trigger the turn-off threshold (+40mV), the gate voltage is pulled to zero after a very short turn-off delay (see Figure 3).

Turn-Off Blanking

After the gate driver is pulled to zero by V_{DS} reaching the turn-off threshold (+40mV), turn-off blanking is triggered to ensure that the gate driver is off for at least t_{B_ON} to prevent an error trigger on V_{DS} .

Light-Load Latch-Off Function

The gate driver of the MP6924, MP6924A is latched off to save driver loss in light-load condition and improve efficiency.

When the MOSFET's switching cycle conducting period falls below T_{LL} , the MP6924, MP6924A enters light-load mode and latches off the MOSFET after a light-load enter delay, T_{LL-D} (see Figure 4).

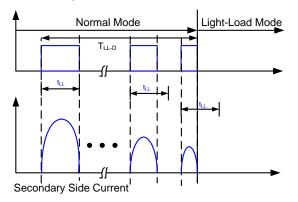


Figure 4: MP6924, MP6924A Entering Light-Load Mode

During light-load mode, the MP6924, MP6924A monitors the body diode conduction time. If this time exceeds $T_{LL} + T_{LL-H}$, the IC exits light-load mode and initiates the gate driver in the next new switching cycle (see Figure 5 and Figure 6).

Light-load enter timing (T_{LL}) is programmable by connecting a resistor (R_{LL}) to LL. By monitoring the LL current (the LL voltage is kept at ~2V internally), T_{LL} can be calculated with Equation (1):

$$T_{LL} = R_{LL}(k\Omega) \cdot \frac{2.3us}{100k\Omega}$$
(1)

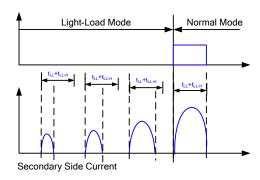


Figure 5: MP6924, MP6924A Exiting Light-Load Mode

If the light-load mode of the MP6924, MP6924A ends during the rectification cycle, the gate driver signal does not appear until the next rectification cycle starts (see Figure 6).

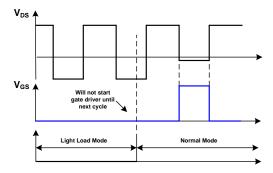


Figure 6: Gate Driver Starts After Exiting Light-Load Mode

Anti-Bounce Logic (MP6924)

The MP6924 has anti-bounce logic, which helps protect the two-channel driver against cross conduction. MP6924A disables this feature.

Figure 7 shows the anti-bounce logic for the two-channel driver. When channel 1 or 2 are turned off, the corresponding channel gate driver is blanked until another channel is switched off.

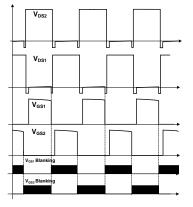


Figure 7: Anti-Bounce Logic of the Gate Driver

APPLICATION INFORMATION

Layout Considerations

Listed below are the main recommendations that should be taken into consideration when designing the PCB.

Sensing for V_D/V_S

- 1. Keep the sensing connections $(V_{D1}/V_{SS}, V_{D2}/V_{SS})$ as close to each of the MOSFETs (drain/source) as possible.
- 2. Keep the two channels' sensing loops separated from each other.
- 3. Make the sensing loop as small as possible (see Figure 8).

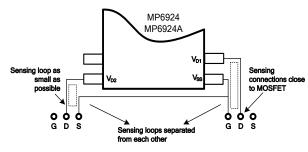


Figure 8: Sensing for V_D/V_S

Figure 9 shows a layout example of the MP6924, MP6924A driving PowerPAK SO8 package MOSFETs with two, separate, small sensing loops.

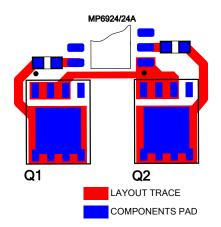


Figure 9: Layout Example for Sensing Loop and V_{DD} Decoupling

V_{DD} Decoupling Capacitor

1. Place a decoupling capacitor no smaller than 1μ F from V_{DD} to PGND close to the IC for adequate filtering (see Figure 10).

System Power Loop

- Keep the two channels' power loops separated from each other (see Figure 10).
 This minimizes the interaction between the two channels' power loops, which may affect the voltage sensing of the IC.
- 2. Make the power loop as small as possible to reduce parasitic inductance.

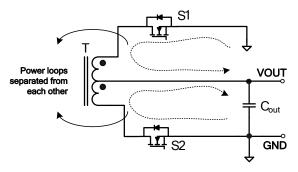
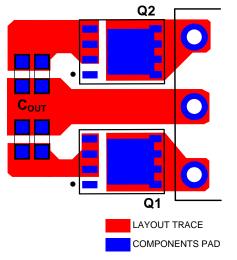


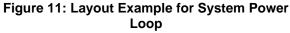
Figure 10: System Power Loop

Figure 11 shows a layout example of the power loop trace, which has a minimized loop length. The two channel power traces do not cross each other.

It is highly recommended to place the driver's sensing loop trace away from the power loop trace (see Figure 11). The sensing loop trace and power loop trace can be placed on different layers to keep them separate from each other.

Do not place the driver IC inside the power loop; this may affect MOSFET voltage sensing.





SR MOSFET Selection and Driver Ability

Power MOSFET selection is a trade-off between $R_{DS(ON)}$ and Q_g . To achieve high efficiency, a MOSFET with a smaller $R_{DS(ON)}$ is recommended. A larger Q_g with a smaller $R_{DS(ON)}$ makes the turn-on/-off speed lower and the power loss larger. For the MP6924, MP6924A, V_{DS} is adjusted at V_{fwd} during the driving period. A MOSFET with a small $R_{DS(ON)}$ is not recommended because the gate driver may be kept at a fairly low level with a small $R_{DS(ON)}$, even when the system load is high, which makes the advantage of the low $R_{DS(ON)}$ inconspicuous.

Figure 12 shows the typical waveform of the LLC on the secondary side. To achieve a fairly high usage of the MOSFET's $R_{DS(ON)}$, it is expected that the MOSFET driver voltage is kept at the maximum level until the last 25% of the SR conduction period. Calculate V_{DS} with Equation (2):

$$V_{\text{DS}} = -R_{\text{ds(ON)}} \cdot \frac{\sqrt{2}}{2} \cdot I_{\text{peak}} = -R_{\text{ds(ON)}} \cdot I_{\text{OUT}} = -V_{\text{fwd}} (2)$$

Where V_{DS} is drain-source voltage of the MOSFET.

The MOSFET's $R_{DS(ON)}$ is recommended to be no lower than $\sim V_{fwd}/I_{OUT}$ (m Ω). For example, in a 10A application with V_{fwd} at 45mV, the $R_{DS(ON)}$ of the MOSFET is recommended to be no lower than 4.5m Ω .

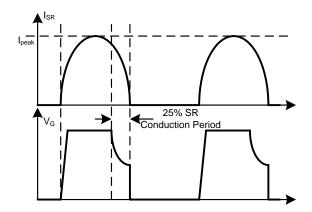


Figure 12: Synchronous Rectification Typical Waveform in LLC

 Q_g of the MOSFET affects the turn-on and turnoff delay. Figure 3 indicates the turn-on delay (t_{Don}) and the turn-off delay (t_{Doff}). t_{Don} indicates how long the body diode conducts before the MOSFET is turned on, while t_{Doff} indicates how long the driver takes to turn off the MOSFET. With a higher turn-on delay, the body diode conduction duration of the MOSFET is longer, which brings down the total efficiency. However, with a higher turn-off delay, the shoot-through risk is higher in CCM operation.

Figure 13 and Figure 14 show the t_{Don} and t_{Doff} of the MP6924, MP6924A according to different C_{load} values.

Turn-On Delay vs. CLOAD

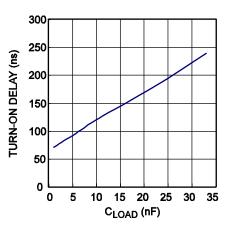


Figure 13: Turn-On Delay vs. Cload

Turn-Off Delay vs. CLOAD

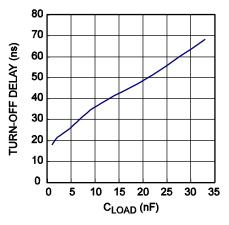


Figure 14: Turn-Off Delay vs. Cload

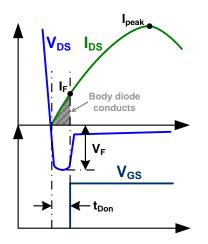


Figure 15: Turn-On Delay Effect on Efficiency

Figure 15 shows how t_{Don} affects system efficiency. During t_{Don} , the body diode of the SR MOSFET conducts, which leads to a power loss that can be calculated with Equation (3):

$$P_{on} \approx \frac{V_{F} \cdot I_{F}}{2} \cdot 2f_{s} \cdot t_{Don} = V_{F} \cdot I_{F} \cdot f_{s} \cdot t_{Don} \quad (3)$$

Where V_F is the body diode forward voltage drop, I_F is the switching current when the turnon delay (t_{Don}) has ended, and f_s is the switching frequency.

When considering the switching current as a complete sine wave, I_F can be estimated with Equation (4) and Equation (5):

$$I_{\rm F} = I_{\rm peak} \cdot \sin(2 \cdot f_{\rm s} \cdot t_{\rm Don} \cdot \pi) \tag{4}$$

$$I_{\text{peak}} \approx \frac{\pi}{2} \cdot I_{\text{out}}$$
 (5)

Where I_{peak} is the peak switching current through the MOSFET, and I_{out} is the system output current.

When plugging the values from Equation (4) and Equation (5) into Equation (3), the turn-on delay power loss through the SR MOSFET's body diode can be derived with Equation (6):

$$\mathsf{P}_{\mathsf{on}} = \frac{\pi}{2} \cdot \mathsf{I}_{\mathsf{out}} \cdot \mathsf{V}_{\mathsf{F}} \cdot \mathsf{f}_{\mathsf{s}} \cdot \mathsf{t}_{\mathsf{Don}} \cdot \mathsf{sin}(2 \cdot \mathsf{f}_{\mathsf{s}} \cdot \mathsf{t}_{\mathsf{Don}} \cdot \pi) (6)$$

Figure 16 shows how different turn-on delay values affect efficiency according to different output voltages. To keep the body diode conduction loss at a fairly low level (below 0.5% of the output power), the turn-on delay is recommended to be less than 5% of the switching cycle. For example, in a $f_{sw} = 200$ kHz LLC system, the switching cycle is ~5µs, and it is recommended to select the MOSFET to make $t_{Don} < 250$ ns.

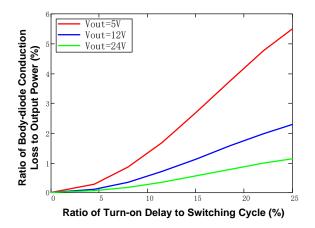


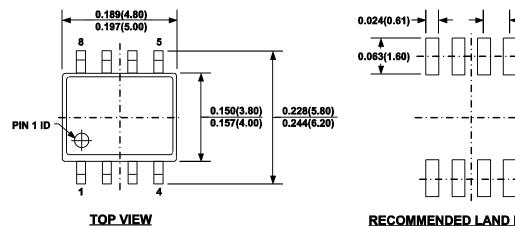
Figure 16: Turn-On Delay vs. Power Loss

The turn-off delay (t_{Doff}) is critical in some fast transient CCM applications. Choose the MOSFET to make t_{Doff} below the CCM current transient duration. Otherwise, the MOSFET may need to be selected with a lower Q_g , or an external totem pole driver circuit may be added to prevent shoot-through.

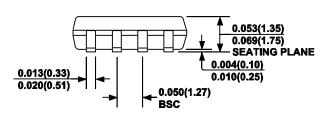


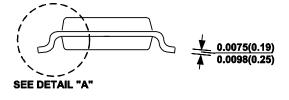
SOIC-8

PACKAGE INFORMATION



RECOMMENDED LAND PATTERN

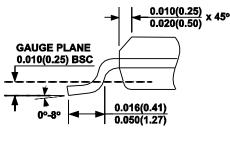




-0.050(1.27)

0.213(5.40)

SIDE VIEW



FRONT VIEW

DETAIL "A"

NOTE:

- 1) CONTROL DIMENSION IS IN INCHES. DIMENSION IN **BRACKET IS IN MILLIMETERS.**
- 2) PACKAGE LENGTH DOES NOT INCLUDE MOLD FLASH, **PROTRUSIONS OR GATE BURRS.**
- 3) PACKAGE WIDTH DOES NOT INCLUDE INTERLEAD FLASH **OR PROTRUSIONS.**
- 4) LEAD COPLANARITY (BOTTOM OF LEADS AFTER FORMING) SHALL BE 0.004" INCHES MAX.
- 5) DRAWING CONFORMS TO JEDEC MS-012, VARIATION AA.
- 6) DRAWING IS NOT TO SCALE.

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